## NSN 5961-01-174-1221

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-174-1221 **Inclosure Material:** Glass **Overall Length:** Between 0.160 inches and 0.260 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.080 inches and 0.120 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-41 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 repetitive peak reverse voltage, peak total value and 48.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute and 25.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: